

## Supporting Information

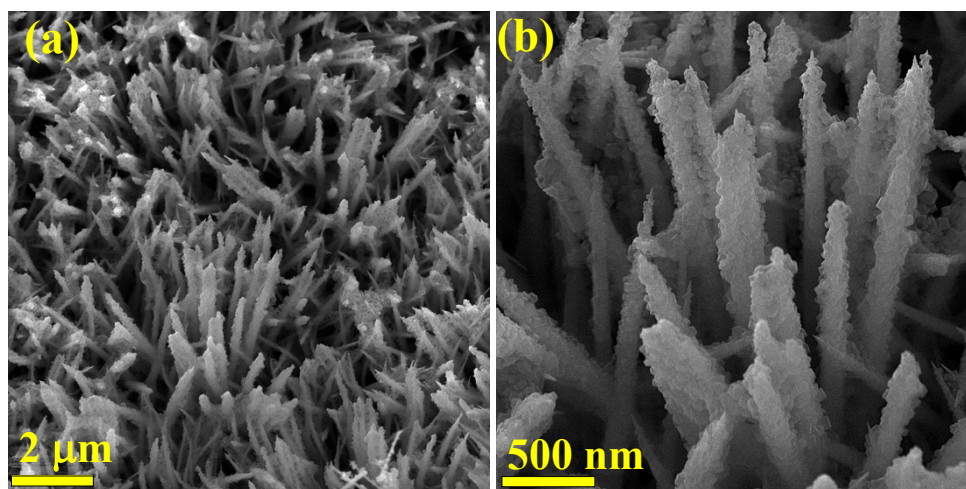
# Revolutionizing energy storage with advanced reduced graphene oxide-wrapped MnSe@CoSe@FeSe<sub>2</sub> nanowires

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**Fig. S1** (a, b) FESEM images of the NF@MCFS300.

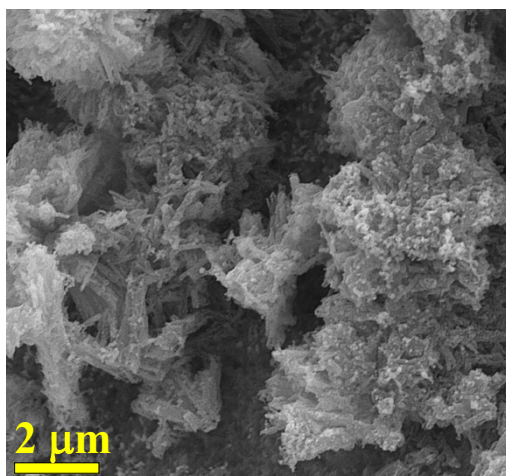


Fig. S2 FESEM images of the NF@MCFS600.

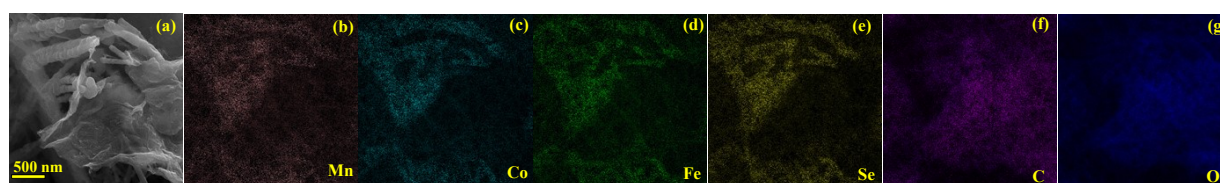


Fig. S3 FESEM mapping images of the NF@MCFS500-rGO.

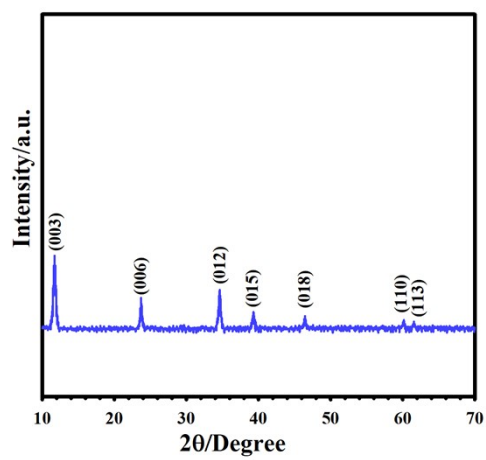


Fig. S4 XRD pattern of the MCFLDH.

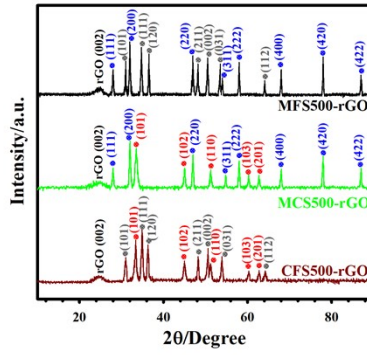


Fig. S5 XRD patterns of the MFS500-rGO, CFS500-rGO, and MCS500-rGO.

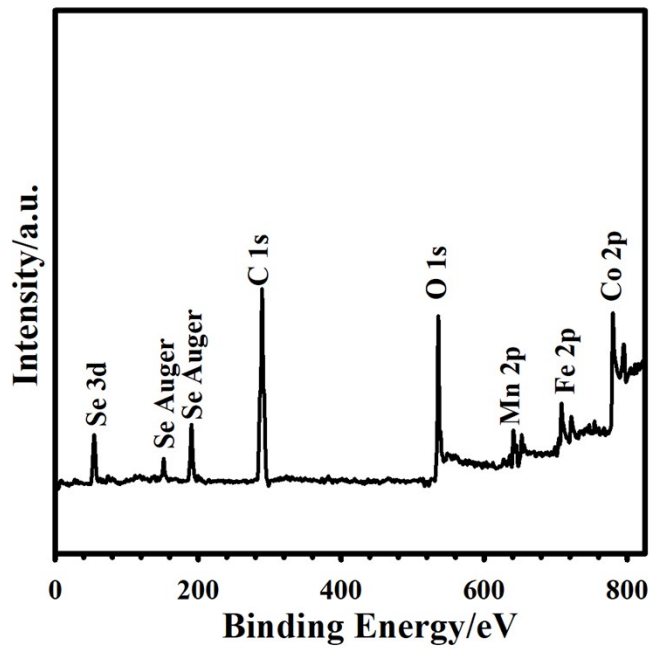
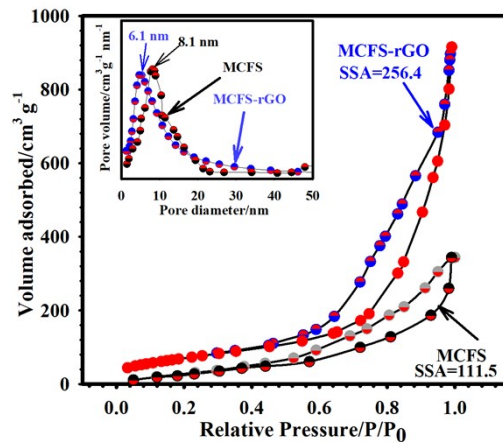
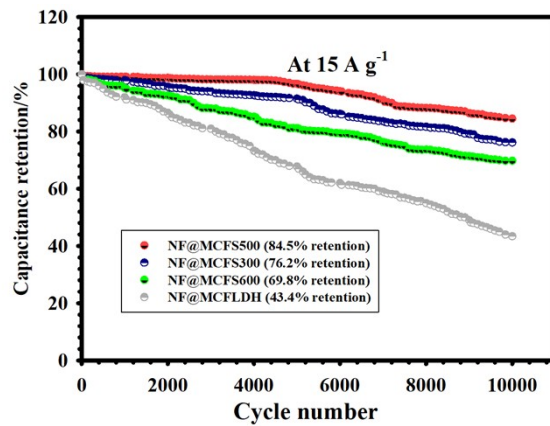


Fig. S6 Comprehensive XPS profile of the MCFS500-rGO.



**Fig. S7** BET graphs of the MCFS500-rGO and MCFS500 along with their corresponding BJH graphs (inset).



**Fig. S8** Longevity of the NF@MCFLDH, NF@MCFS300, NF@MCFS500, and NF@MCFS600 electrodes at 15 A g<sup>-1</sup>.

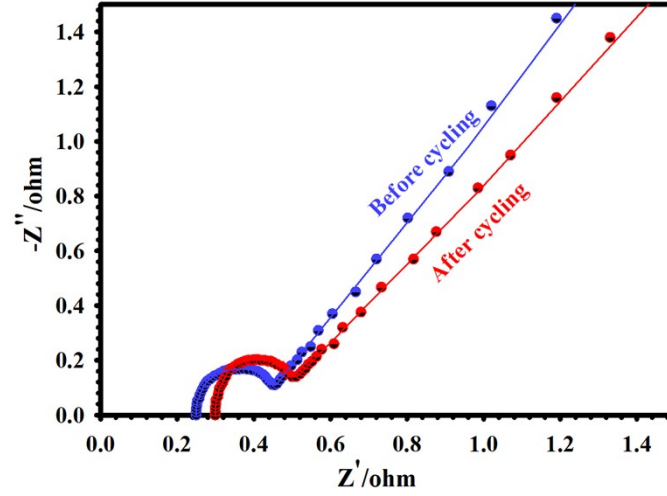


Fig. S9 EIS curves of the NF@MCFS500-rGO before and after 10000 cycles.

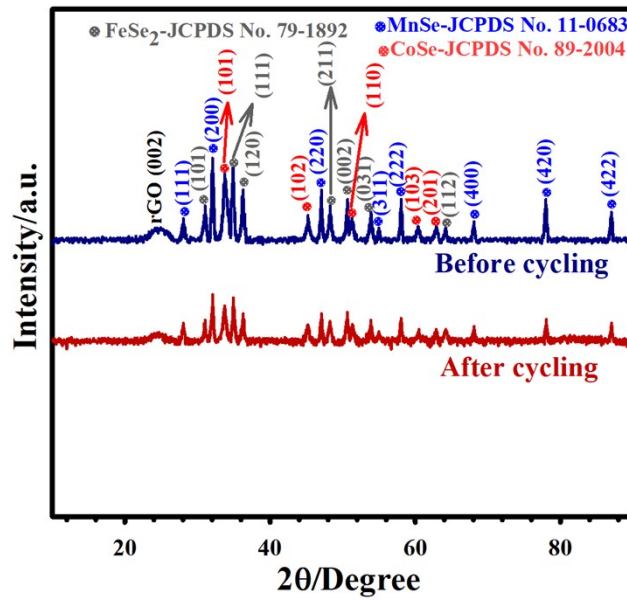
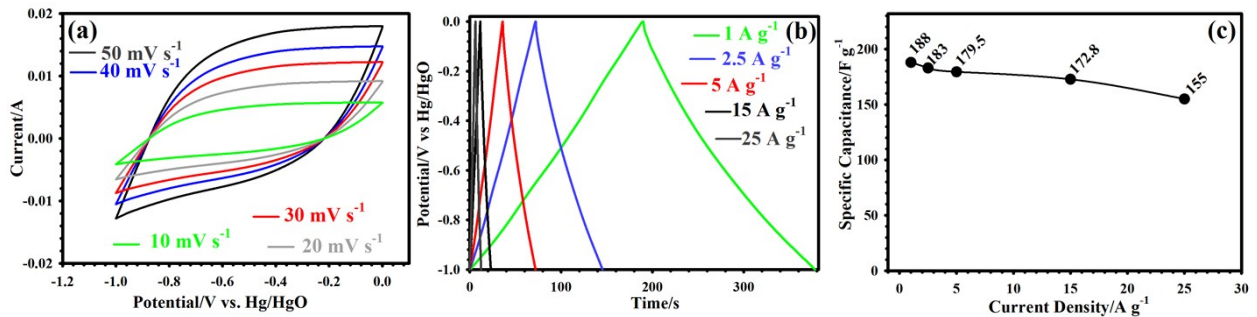
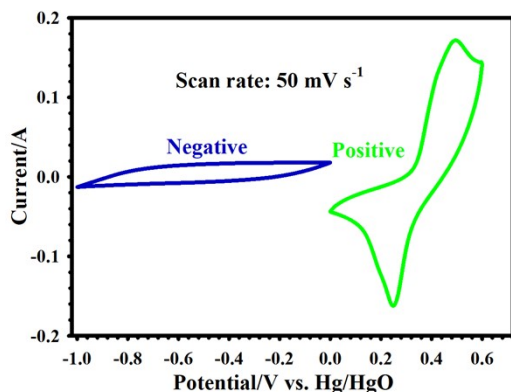


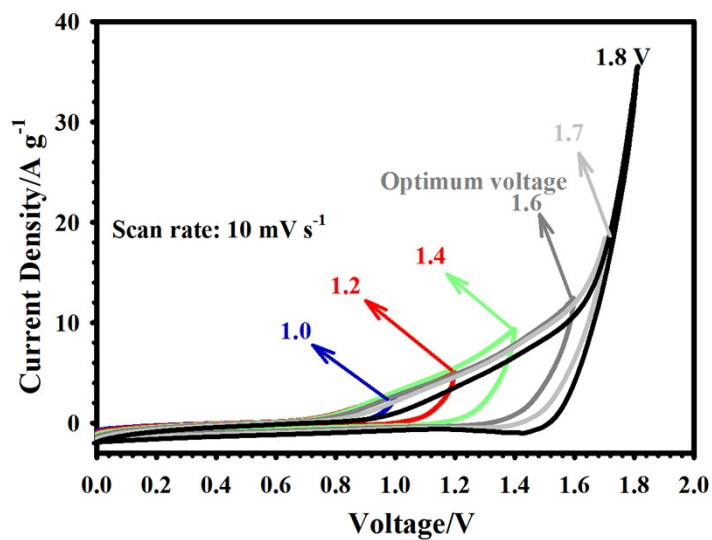
Fig. S10 XRD pattern of the MCFS500-rGO before and after 10000 GCD cycles.



**Fig. S11** (a) CV plots of the AC from 10 to 50 mV s<sup>-1</sup>. (b) GCD plots of the AC from 1 to 25 A g<sup>-1</sup>. (c) Rate capability of the AC electrode.



**Fig S. 12** CV plots of AC (negative electrode) and NF@MCFS500-rGO (positive electrode) at 50 mV s<sup>-1</sup> in three-electrode cell.



**Fig. S13** CV plots of the AC/NF@MCFS500-rGO at various potential window at 10 mV s<sup>-1</sup> from 1.0 to 1.8 V.

**Table S1.** Comparison of the supercapacitive performance of the NF@MCFS500-rGO with other

Composition	Capacitance (F/g)	Cycles, retention	Rate capability	ED (Wh kg <sup>-1</sup> )	Reference
NiSe-Ni <sub>0.85</sub> Se	1486.6 at 1 A g <sup>-1</sup>	5000, 80%	69% at 20 A g <sup>-1</sup>	41	1
CuSe@MnSe	1270.6 at 1 A g <sup>-1</sup>	7000, 91.62%	60.3% at 30 A g <sup>-1</sup>	19.54	2
Sn-Co(OH) <sub>2</sub>	1441.8 at 1 A g <sup>-1</sup>	5000, 84.3%	49.5% at 5 A g <sup>-1</sup>	-	3
NiCoP/Co(OH) <sub>2</sub>	1604 at 1 A g <sup>-1</sup>	5000, 91.1%	81.8% at 20 A g <sup>-1</sup>	38.4	4
Ni <sub>0.85</sub> Se	1354 at 1 A g <sup>-1</sup>	300, 90%	49.55% at 30 A g <sup>-1</sup>	40.7	5
MnCo <sub>2</sub> O <sub>4</sub> /MnO <sub>2</sub>	1539 at 1 A g <sup>-1</sup>	10000, 95.5 %	51.2% at 20 A g <sup>-1</sup>	48.78	6
CoSe <sub>2</sub> /NC-NF	1236.5 at 1 A g <sup>-1</sup>	10000, 92%	61.2% at 20 A g <sup>-1</sup>	40.9	7
Cerium Selenide	451.4 at 1 A g <sup>-1</sup>	4000, 70.7%	65% at 15 A g <sup>-1</sup>	36.1	8
Co <sub>x</sub> Ni <sub>1-x</sub> Se	918.8 at 1 A g <sup>-1</sup>	4000, 83.9%	47% at 10 A g <sup>-1</sup>	-	9
3DG/ZnSe-SnSe <sub>2</sub>	1515.2 at 1 A g <sup>-1</sup>	3000, 90.1% (3 E)	64.5% at 20 A g <sup>-1</sup>	25.3	10
MnCo <sub>2</sub> O <sub>4</sub> @MoS <sub>2</sub>	512 at 1 A g <sup>-1</sup>	5000, 99.57% (3 E)		36	11
NiCo <sub>2</sub> S <sub>4</sub> @DCCNF)	1474 at 1 A g <sup>-1</sup>	5000, 90.2% (3 E)	80% at 20 A g <sup>-1</sup>	55.6	12
NF@MCFS-rGO	1830 at 1 A g <sup>-1</sup>	10000, 93.25% (3 E)	78.5% at 25 A g <sup>-1</sup>	64.6	This work

previously reported selenide based-electrodes.

## References

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